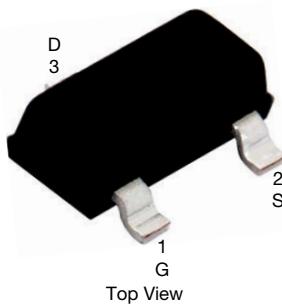


## N-Channel 20 V (D-S) MOSFET

**SOT-23 (TO-236)**

**Marking code:** N2

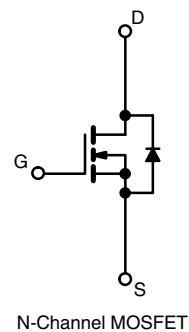
**FEATURES**

- TrenchFET® power MOSFET
- Material categorization:  
for definitions of compliance please see  
[www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**  
Available

**APPLICATIONS**

- Load switching for portable devices
- DC/DC converter


**PRODUCT SUMMARY**

V <sub>DS</sub> (V)	20
R <sub>DS(on)</sub> max. (Ω) at V <sub>GS</sub> = 4.5 V	0.057
R <sub>DS(on)</sub> max. (Ω) at V <sub>GS</sub> = 2.5 V	0.075
Q <sub>g</sub> typ. (nC)	3.5
I <sub>D</sub> (A)	2.9
Configuration	Single

**ORDERING INFORMATION**

Package	SOT-23
Lead (Pb)-free	Si2302CDS-T1-E3
Lead (Pb)-free and halogen-free	Si2302CDS-T1-GE3

**ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

PARAMETER	SYMBOL	5 S	STEADY STATE	UNIT
Drain-source voltage	V <sub>DS</sub>	20	20	V
Gate-source voltage	V <sub>GS</sub>	± 8	± 8	
Continuous drain current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	2.9	2.6	A
	T <sub>A</sub> = 70 °C	2.3	2.1	
Pulsed drain current <sup>b</sup>	I <sub>DM</sub>	10	10	A
Continuous source current (diode conduction) <sup>a</sup>	I <sub>S</sub>	0.72	0.6	
Power dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	0.86	0.71	W
	T <sub>A</sub> = 70 °C	0.55	0.46	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	-55 to +150	°C

**THERMAL RESISTANCE RATINGS**

PARAMETER	SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient <sup>a</sup>	t ≤ 5 s	R <sub>thJA</sub>	120	145
	Steady state		140	175
Maximum junction-to-foot	R <sub>thJF</sub>	62	78	°C/W

**Notes**

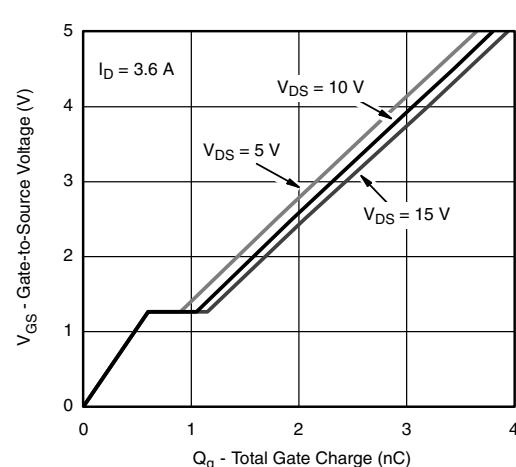
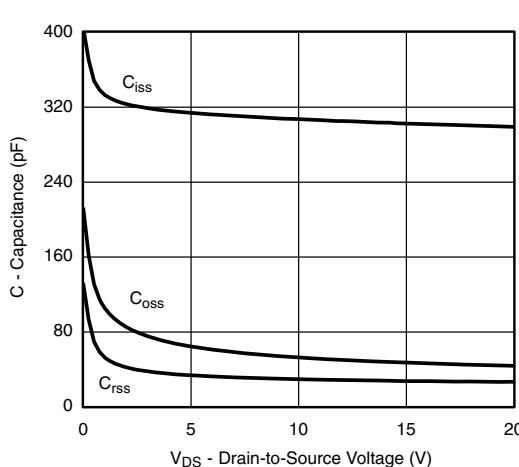
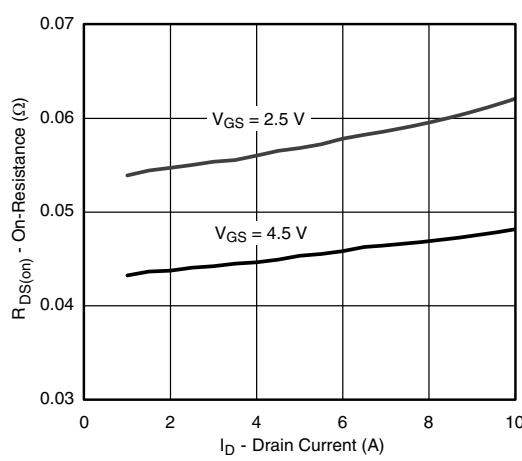
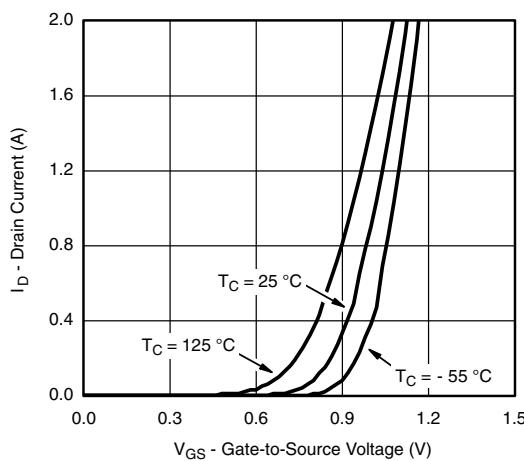
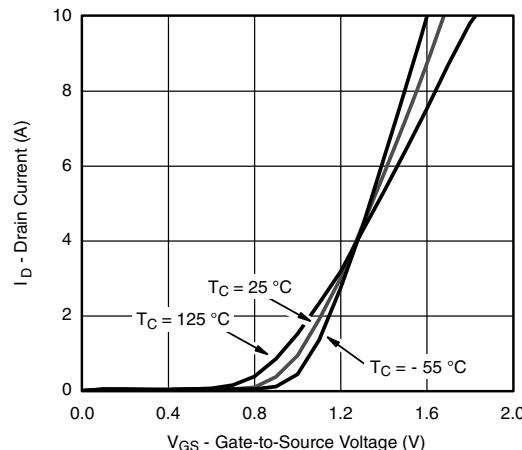
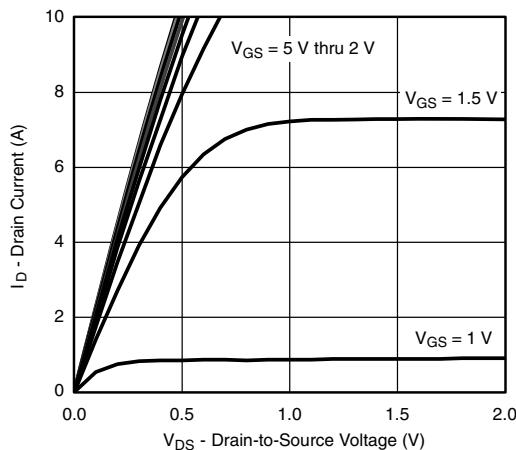
- Surface mounted on 1" x 1" FR4 board
- Pulse width limited by maximum junction temperature

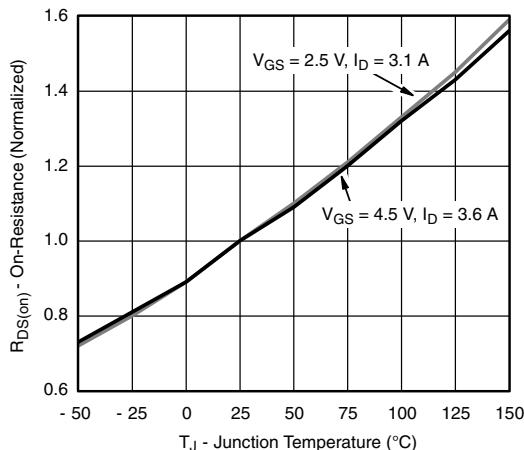
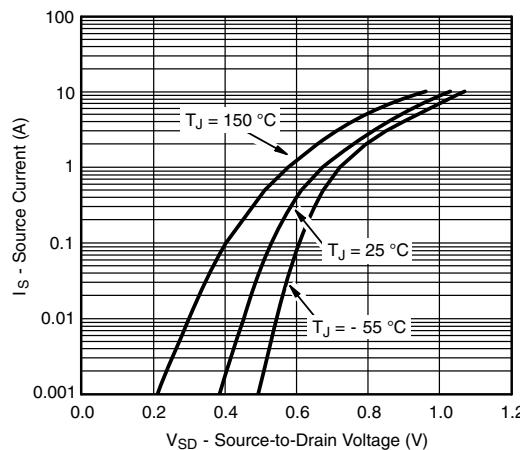
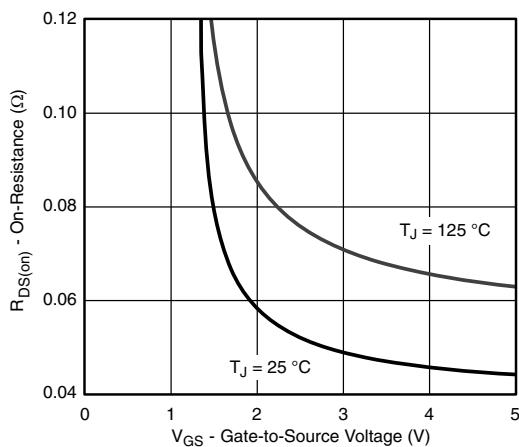
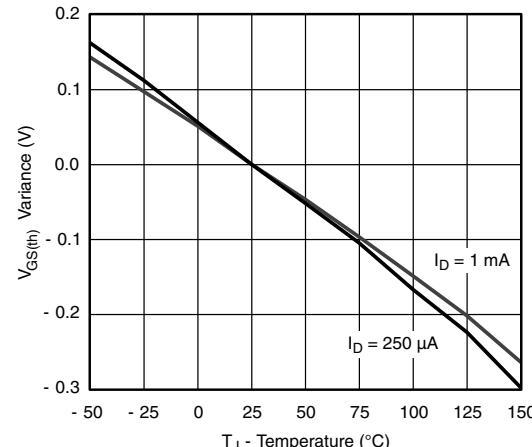
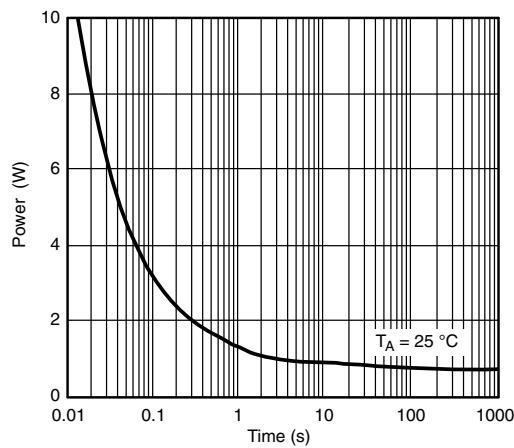
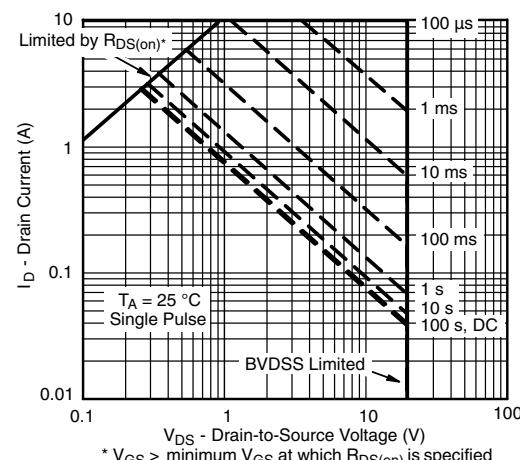
<b>SPECIFICATIONS</b> ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)						
<b>PARAMETER</b>	<b>SYMBOL</b>	<b>TEST CONDITIONS</b>	<b>LIMITS</b>			<b>UNIT</b>
			<b>MIN.</b>	<b>TYP.</b>	<b>MAX.</b>	
<b>Static</b>						
Drain-source breakdown voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}$ , $I_D = 250 \mu\text{A}$	20	-	-	$\text{V}$
Gate-threshold voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}$ , $I_D = 250 \mu\text{A}$	0.40	-	0.85	
Gate-body leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}$ , $V_{GS} = \pm 8 \text{ V}$	-	-	$\pm 100$	nA
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 20 \text{ V}$ , $V_{GS} = 0 \text{ V}$	-	-	0.1	$\mu\text{A}$
		$V_{DS} = 20 \text{ V}$ , $V_{GS} = 0 \text{ V}$ , $T_J = 50^\circ\text{C}$	-	-	4	
		$V_{DS} = 20 \text{ V}$ , $V_{GS} = 0 \text{ V}$ , $T_J = 70^\circ\text{C}$	-	-	15	
On-state drain current <sup>a</sup>	$I_{D(\text{on})}$	$V_{DS} \geq 10 \text{ V}$ , $V_{GS} = 4.5 \text{ V}$	6	-	-	A
Drain-source on-resistance <sup>a</sup>	$R_{DS(\text{on})}$	$V_{GS} = 4.5 \text{ V}$ , $I_D = 3.6 \text{ A}$	-	0.045	0.057	$\Omega$
		$V_{GS} = 2.5 \text{ V}$ , $I_D = 3.1 \text{ A}$	-	0.056	0.075	
Forward transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 5 \text{ V}$ , $I_D = 3.6 \text{ A}$	-	13	-	S
Diode forward voltage	$V_{SD}$	$I_S = 0.95 \text{ A}$ , $V_{GS} = 0 \text{ V}$	-	0.7	1.2	V
<b>Dynamic <sup>b</sup></b>						
Total gate charge	$Q_g$	$V_{DS} = 10 \text{ V}$ , $V_{GS} = 4.5 \text{ V}$ , $I_D = 3.6 \text{ A}$	-	3.5	5.5	nC
Gate-source charge	$Q_{gs}$		-	0.6	-	
Gate-drain charge	$Q_{gd}$		-	0.45	-	
Gate resistance	$R_g$	$f = 1 \text{ MHz}$	2	4	8	$\Omega$
<b>Switching</b>						
Turn-on delay time	$t_{d(\text{on})}$	$V_{DD} = 10 \text{ V}$ , $R_L = 2.78 \Omega$ $I_D \geq 3.6 \text{ A}$ , $V_{GEN} = 4.5 \text{ V}$ , $R_g = 1 \Omega$	-	8	15	ns
Rise time	$t_r$		-	7	15	
Turn-off delay time	$t_{d(\text{off})}$		-	30	45	
Fall time	$t_f$		-	7	15	
Source-drain reverse recovery time	$t_{rr}$		-	8.5	15	
Body diode reverse recovery charge	$Q_{rr}$	$I_F = 3.6 \text{ A}$ , $di/dt = 100 \text{ A}/\mu\text{s}$	-	2	4	nC

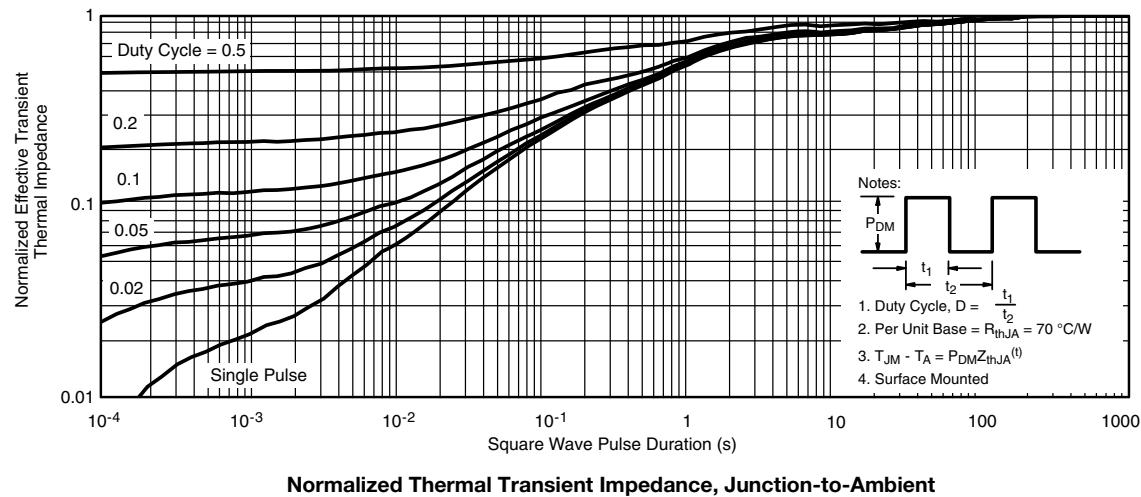
**Notes**

- a. Pulse test: Pulse width  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 2 \%$
- b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

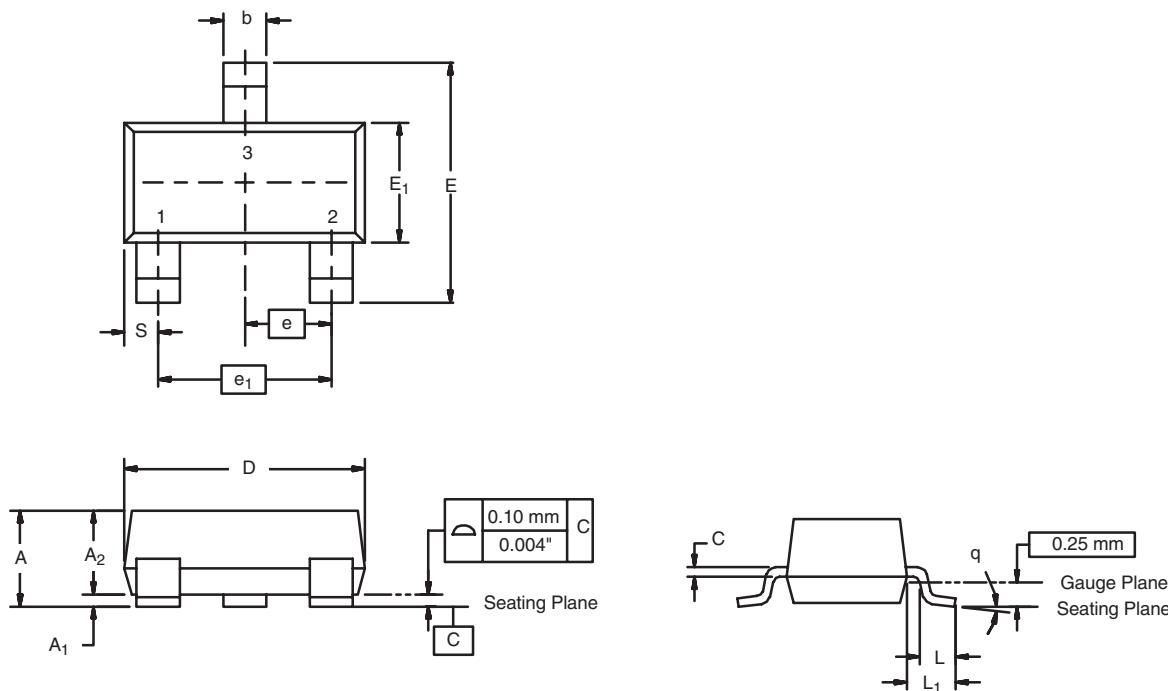
**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)


**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)

**On-Resistance vs. Junction Temperature**

**Source-Drain Diode Forward Voltage**

**On-Resistance vs. Gate-to-Source Voltage**

**Threshold Voltage**

**Single Pulse Power**

**Safe Operating Area, Junction-to-Ambient**

**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)


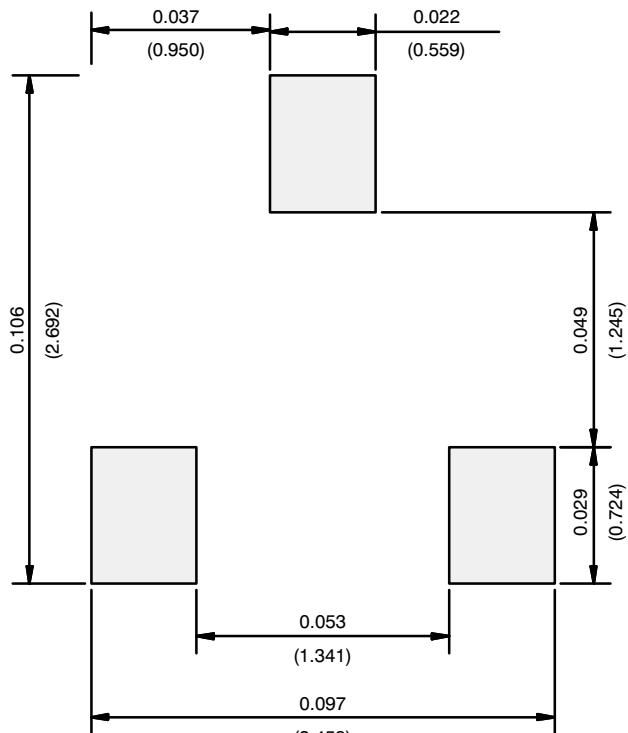
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### SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A <sub>1</sub>	0.01	0.10	0.0004	0.004
A <sub>2</sub>	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E <sub>1</sub>	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e <sub>1</sub>	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L <sub>1</sub>	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°

ECN: S-03946-Rev. K, 09-Jul-01  
DWG: 5479

**RECOMMENDED MINIMUM PADS FOR SOT-23**

Recommended Minimum Pads  
Dimensions in Inches/(mm)

[Return to Index](#)



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